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Tel: +86-755-8981 8866 Fax: +86-755-8427 6832

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Address: A1208, Overseas Decoration Building, #122 Zhenhua RD., Futian, Shenzhen, China







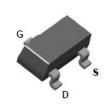


April 2008

MMBF102 N-Channel RF Amplifier

Features

- · This device is designed primarily for electronic switching applications such as low On Resistance analog switching.
- Sourced from process 50



SOT - 23 Mark: 61Y

Absolute Maximum Ratings* T_a =25°C unless otherwise noted

Symbol	Parameter	Value	Units
V _{DG}	Drain-Gate Voltage	25	V
V _{GS}	Gate-Source Voltage	-25	V
I _{GF}	Forward Gate Current	10	mA
T _J , T _{STG}	Storage Temperature Range	-55 to +150	°C

^{*} These ratings are limiting values above which the serviceability of any semiconductor device may be impaired.

Thermal Characteristics T_a=25°C unless otherwise noted

Symbol Parameter		Value	Unit
$R_{\theta JA}$	Thermal Resistance, Junction to Ambient	556	°C/W
P_{D}	Total Device Dissipation(T _C =25°C) Derate above 25°C	225 1.8	mW mW/°C

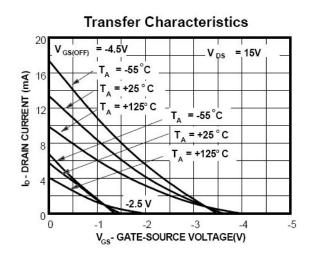
^{*}Device mounted on FR-4 PCB 1.6" X 1.6" X 0.06".

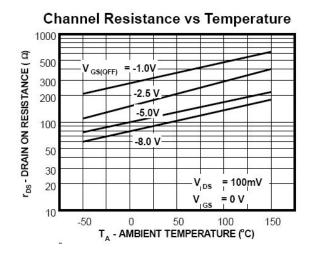
¹⁾ These ratings are based on a maximum junction temperature of 150 degrees C.

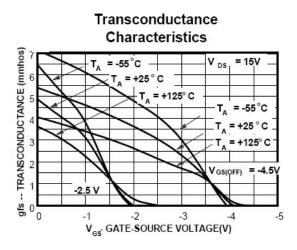
2) These are steady state limits. The factory should be consulted on applications involving pulsed or low duty cycle operations.

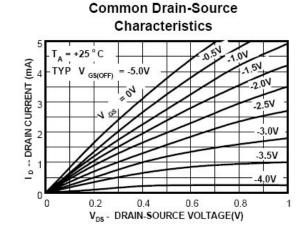
$\textbf{Electrical Characteristics*} \ \, \mathbf{T_{a}\text{=}25^{\circ}C} \ \, \mathbf{unless \ otherwise \ noted}$

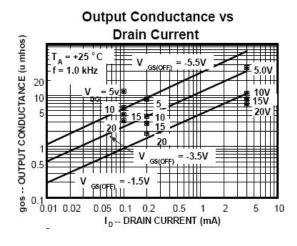
Symbol	Parameter	Test Conditions	Min.	Max.	Units
Off Charac	teristics				
V _{(BR)GSS}	Gate-Source Breakdown Voltage	$I_G = -1.0 \mu A, V_{DS} = 0$	-25		V
I _{GSS}	Gate Reverse Current	V _{GS} = -15V, V _{DS} = 0 T = 100°C		-2.0 -2.0	nA μA
V _{GS(off)}	Gate-Source Cutoff Voltage	V _{DS} = 15V, I _D = 2nA		-8.0	V
V _{GS}	Gate-Source Voltage	V _{DS} = 15V, I _D = 200μA	-0.5	-7.5	V
On Charac	teristics *	•			•
I _{DSS}	Zero-Gate Voltage Drain Current	V _{DS} = 15V, V _{GS} = 0	2.0	20	mA
gfs	Forward Transconductance	V _{GS} = 0V, V _{DS} = 15V, f = 1kHz	2000	7500	μS
Small Sign	al Chracteristics			•	
C _{ISS}	Common-Source Input Capacitance	V _{GS} = 0V, V _{DS} = 15V, f = 1MHz		7.0	pF
C _{RSS}	Common-Source Reverse Transfer Capacitance	V _{GS} = 0V, V _{DS} = 15V, f = 1MHz		3.0	pF

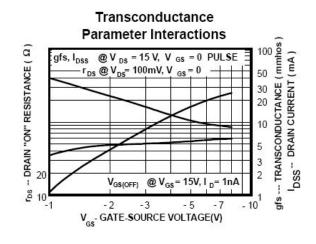


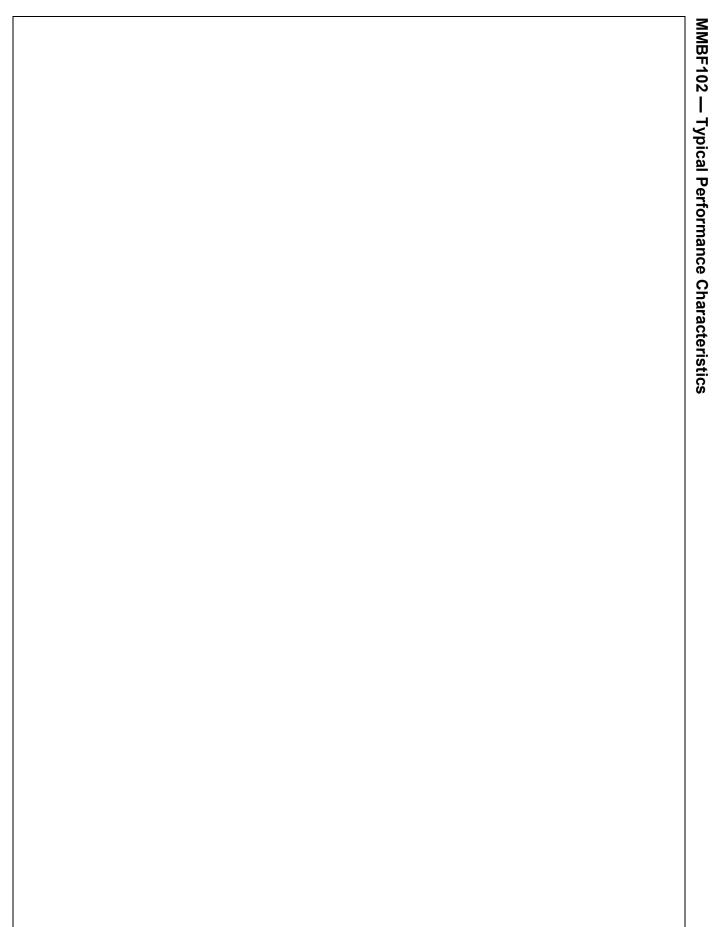


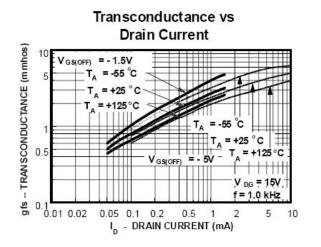


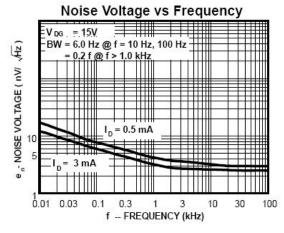


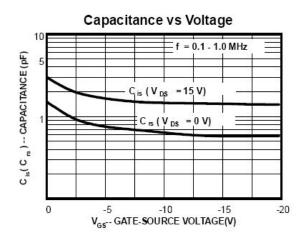


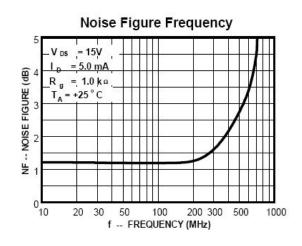


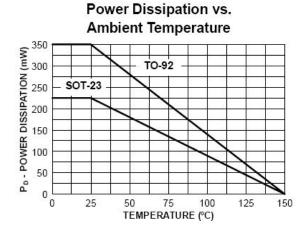


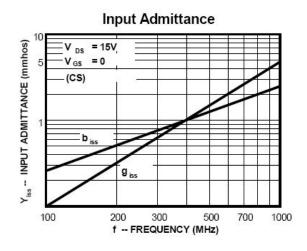


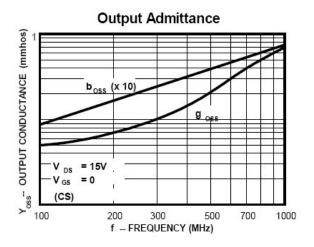


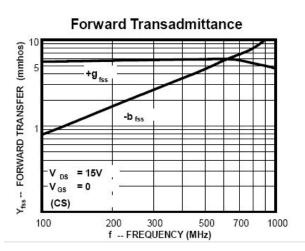


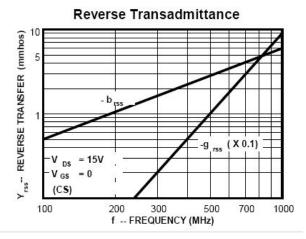


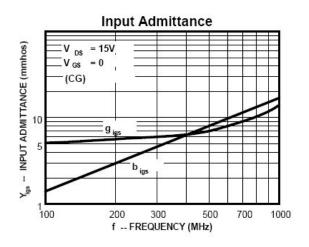


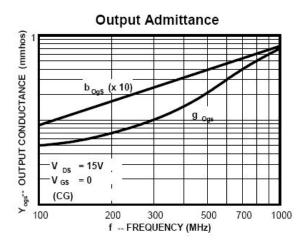


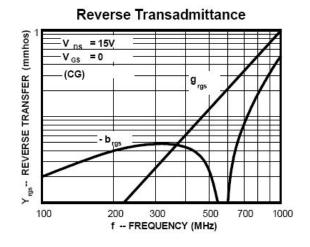










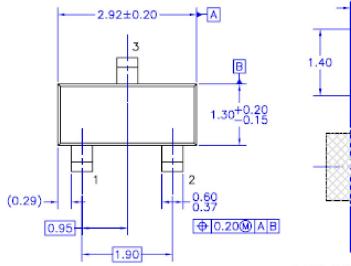


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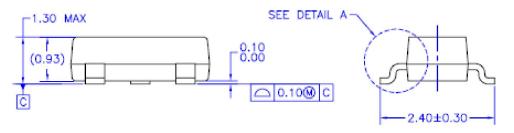
Package Dimension

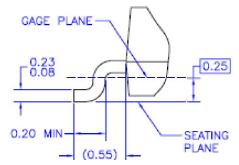
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0.95





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